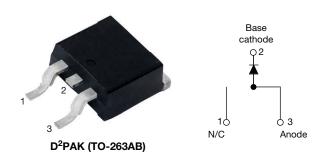


VS-20TQ035S-M3, VS-20TQ040S-M3, VS-20TQ045S-M3

www.vishay.com

Vishay Semiconductors

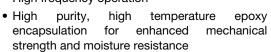
High Performance Schottky Rectifier, 20 A



PRIMARY CHARACTERISTICS								
I _{F(AV)}	20 A							
V_{R}	35 V, 40 V, 45 V							
V _F at I _F	0.51 V							
I _{RM} typ.	105 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	27 mJ							
Package	D ² PAK (TO-263AB)							
Circuit configuration	Single							

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-20TQ... Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform	20	A						
V _{RRM}	Range	35 to 45	V						
I _{FSM}	t _p = 5 μs sine	1800	A						
V _F	20 A _{pk} , T _J = 125 °C	0.51	V						
T _J	Range	-55 to +150	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-20TQ035S-M3	VS-20TQ040S-M3	VS-20TQ045S-M3	UNITS			
Maximum DC reverse voltage	V_R	35	40	45	V			
Maximum working peak reverse voltage	V_{RWM}	33	40	45	v			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS			
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 116 °C	20				
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load	1800	Α		
non-repetitive surge current See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	400			
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 4 \text{A}, L = 3.40 \text{H}$	27	mJ			
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim	4	Α			

VS-20TQ035S-M3, VS-20TQ040S-M3, VS-20TQ045S-M3

www.vishay.com

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS			
Maximum forward voltage drop See fig. 1		20 A	T _{.1} = 25 °C	0.57	V		
	V _{FM} ⁽¹⁾	40 A	1j=25 C	0.73			
	VFM (1)	20 A	T 105 %C	0.51			
		40 A	- T _J = 125 °C	0.67			
Maximum various la alcono accument	1 (1)	T _J = 25 °C	V Dated V	2.7	mA		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	150			
Typical reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	105	mA		
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C		1400	pF		
Typical series inductance	L _S	Measured lead to lead 5 mm	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs			

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	ge	T _J , T _{Stg}		-55 to 150	°C		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4		°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50	O/ VV		
Approximate weight				2	g		
Approximate weight				0.07	OZ.		
Marinting toward	minimum			6 (5)	kgf · cm		
Mounting torque	maximum			12 (10)	(lbf · in)		
Marking device			Case style D ² PAK (TO-263AB)	20TC	035S 040S 045S		

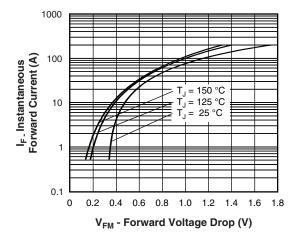


Fig. 1 - Maximum Forward Voltage Drop Characteristics

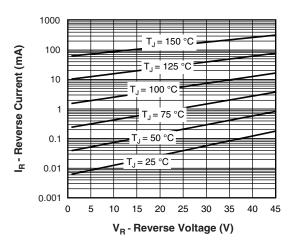


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

www.vishay.com

Vishay Semiconductors

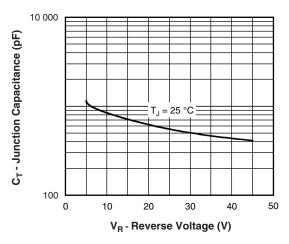


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

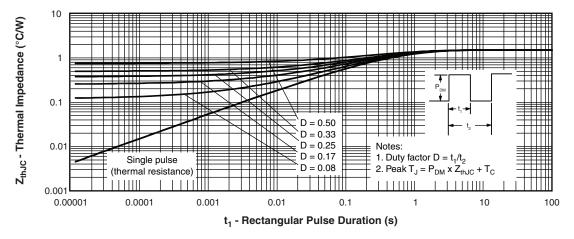


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

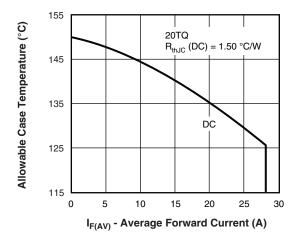


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

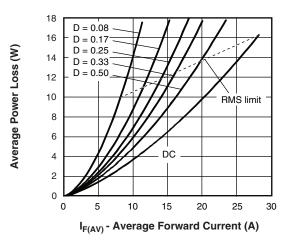


Fig. 6 - Forward Power Loss Characteristics

www.vishay.com

VS-20TQ035S-M3, VS-20TQ040S-M3, VS-20TQ045S-M3

Vishay Semiconductors

100

t_p - Square Wave Pulse Duration (μs)

1000

10 000

Fig. 7 - Maximum Non-Repetitive Surge Current

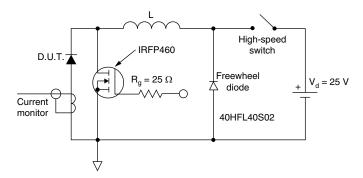
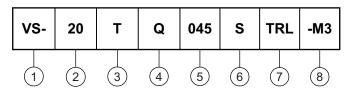


Fig. 8 - Unclamped Inductive Test Circuit

ORDERING INFORMATION TABLE





Vishay Semiconductors product

Current rating (20 A)

Package: T = TO-220

Schottky "Q" series 035 = 35 V 040 = 40 VVoltage ratings

 $S = D^2PAK$

100 10

• None = tube

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 -M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

045 = 45 V



VS-20TQ035S-M3, VS-20TQ040S-M3, VS-20TQ045S-M3

www.vishay.com

Vishay Semiconductors

ORDERING INFORMATION										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-20TQ035S-M3	50	1000	Antistatic plastic tubes							
VS-20TQ035STRR-M3	800	800	13" diameter reel							
VS-20TQ035STRL-M3	800	800	13" diameter reel							
VS-20TQ040S-M3	50	1000	Antistatic plastic tubes							
VS-20TQ040STRR-M3	800	800	13" diameter reel							
VS-20TQ040STRL-M3	800	800	13" diameter reel							
VS-20TQ045S-M3	50	1000	Antistatic plastic tubes							
VS-20TQ045STRR-M3	800	800	13" diameter reel							
VS-20TQ045STRL-M3	800	800	13" diameter reel							

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96164					
Part marking information	www.vishay.com/doc?95444					
Packaging information	www.vishay.com/doc?96424					



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	ES NOTES		SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOIES	NOTES	STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3	
A1	0.00	0.254	0.000	0.010			Е	9.65	10.67	0.380	0.420	2, 3	
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3	
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC		
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625		
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110		
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3	
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070		
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC		
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208		

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.